锑化铟HW101A与HE12AF1U12技术参数对比表：

|  |  |  |  |
| --- | --- | --- | --- |
|  | HW101A | HE12AF1U12 | 备注 |
| 品牌 | AKM | NANOS |  |
| 封装 | SOT-143 | SOT-143 |  |
| 工作温度 | -40 ~ +110 ℃ | -40 ~ +120 ℃ |  |
| 输出电压 | 168-370mV | 196-320mV |  |
| 入力阻抗 | 240-550 Ω | 240-550 Ω |  |
| 出力阻抗 | 240-550 Ω | 240-550 Ω |  |
| 不平衡电压 | -7 to 7mV | -7 to 7mV |  |
| 包装 | 3000/pcs | 3000/pcs |  |
|  |  |  |  |

 2017.04.20